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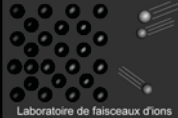
**2015-5**

**Joint ICTP/IAEA Workshop on Advanced Simulation and Modelling  
for Ion Beam Analysis**


*23 - 27 February 2009*

**Elastic Recoil Detection using Heavy Ion beam**

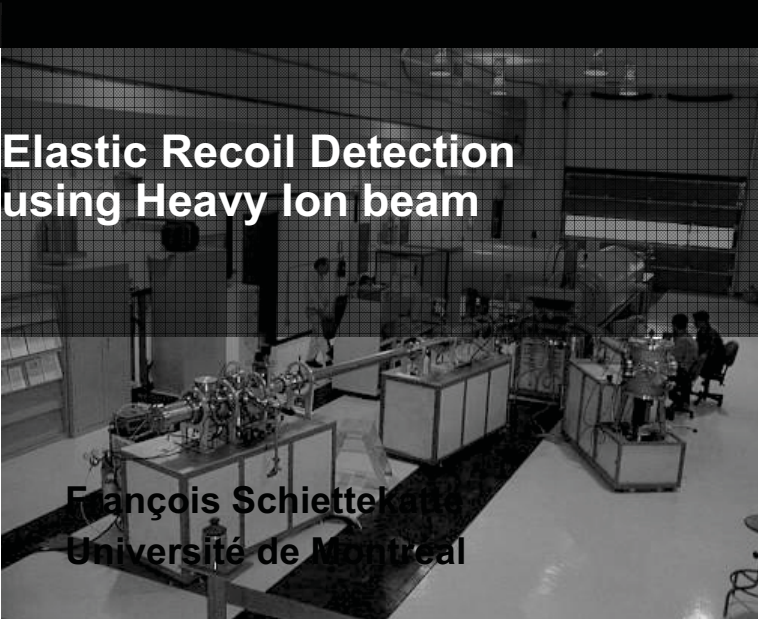
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Canada*




Laboratoire de faisceaux d'ions



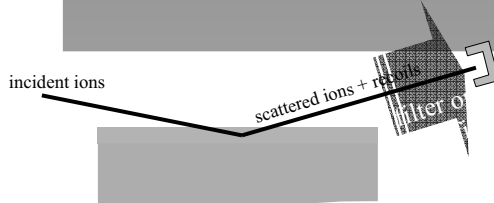
# Elastic Recoil Detection using Heavy Ion beam

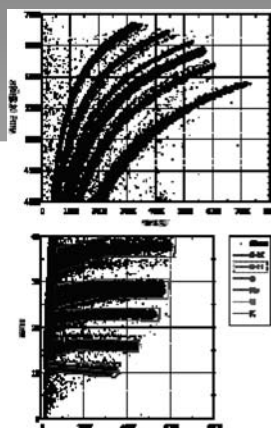


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Université de Montréal

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## Elastic Recoil Detection (ERD)





- He beam
  - ERD complementary to RBS for H detection
  - Low  $H \, dE/dx \times \text{absorber} = \text{bad depth resolution}$ 
    - Electrostatic filters can do a good job
  - Still, the contribution of the other elements to the RBS spectrum are piled up on each other
- Since atoms contained in the material are recoiled, we can detect them and get a spectrum for each
  - Requires beam heavy enough and of enough high energy to recoil target atoms

$$E_2 = \frac{4M_1M_2}{(M_1 + M_2)^2} \cos^2(\theta) E_1$$

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## HI-ERD: the big artillery



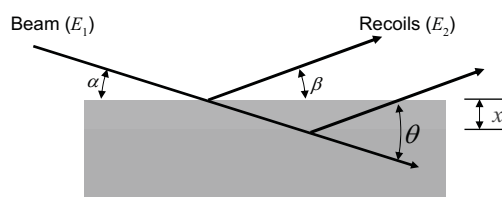
...although IMEC has a nice implementation of ERD-TOF on a 1.7 MV Tandemtron



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## From one ion to several ions



$$Nt(x) = \frac{Yield}{slope} \frac{\partial S(x)}{\partial x} \frac{\sin \alpha}{\left(\frac{d\sigma}{d\Omega}\right) \Delta\Omega q}$$

$$S(x) = K \frac{1}{\sin \alpha} \int_0^x \frac{dE_1(x')}{dx} dx' + \frac{1}{\sin \beta} \int_0^x \frac{dE_2(x')}{dx} dx'$$

- Heavy ions
  - Higher stopping power: potentially better depth resolution
  - Damage? More event per incident ion
- Need to know for the heavy ion beam and each recoil
  - Stopping power in compounds
  - Energy straggling
  - Detector calibration
  - Detector resolution
  - Multiple scattering
    - $(Z_1 Z_2 / E)^2 + + +$

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## Main ion identification systems

- critical angle

$$\theta_{scat} < \arcsin M_1/M_2$$

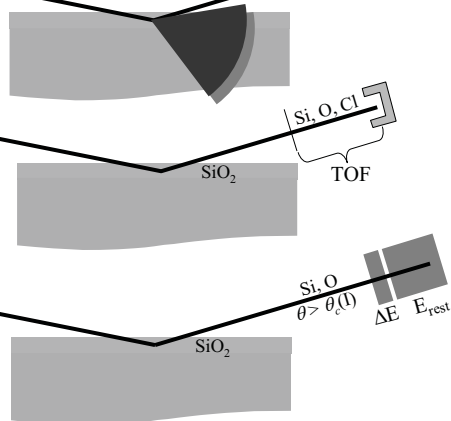
30 MeV Cl

- TOF

100 MeV I

- E- $\Delta E$

$$M_{beam} \gg M_{layer} \gg M_{substrate}$$



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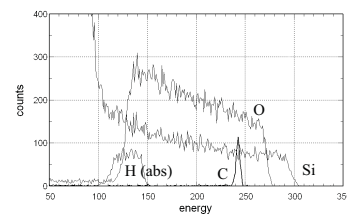
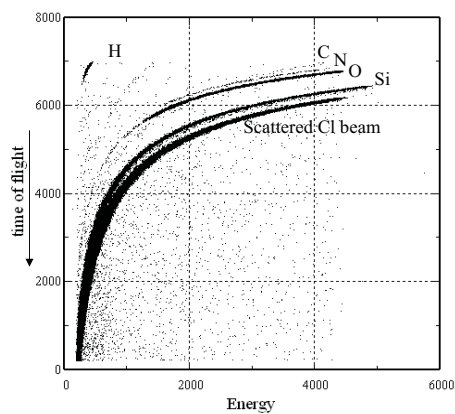
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## Time-of-Flight

30 MeV Cl

650 nm SiO<sub>2</sub>

Si, O, Cl  
ToF

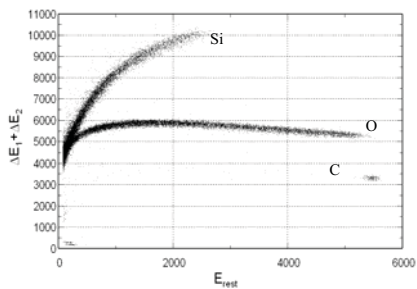


- + good energy resolution
- + energy from time (calibration once)
- small solid angle (<1 mstr)
- detection efficiency problems  $Z \leq 4$

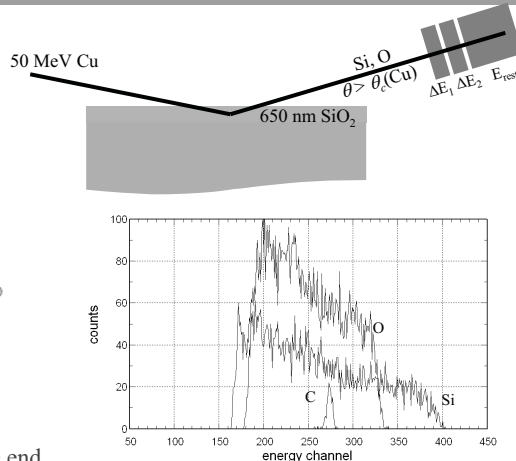
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## E-ΔE (gas counter)



- + large solid angle
- + angular resolution (blocking)
- energy resolution not very good due to straggling in entrance membrane
- H won't stop in the detector: SBD at the end

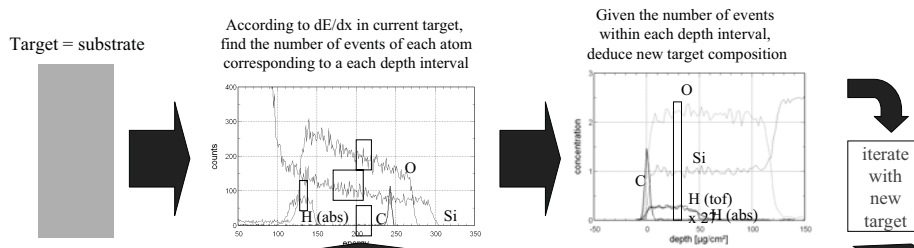


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## Depth profiles from HI-ERD spectra

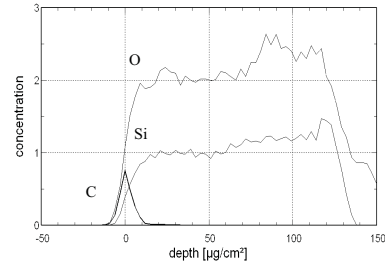
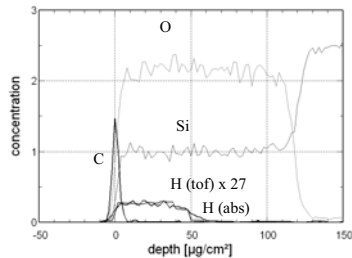
- Depth profiles
  - One spectrum per target atom
    - Sometimes, heavy elements from HI-RBS
  - Iterative procedure to extract depth profiles
    - Depth profile still contains all energy broadening effects: simulation needed to account for them



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## Comparing depth profiles of TOF & gas-counter



(all events: kinetic correction)

- depth resolution\*:
  - from carbon peak:  $\sigma=2.4\pm0.1 \text{ g}/\text{cm}^2$
  - $\text{SiO}_2/\text{Si}$  interface:  $4.9\pm0.4 \text{ g}/\text{cm}^2$ 
    - shallower angle of detection
- depth range  $\sim 250 \text{ g}/\text{cm}^2$  with 50 MeV Cu ( $1 \text{ g}/\text{cm}^2 \sim 4\text{-}5 \text{ nm}$ )

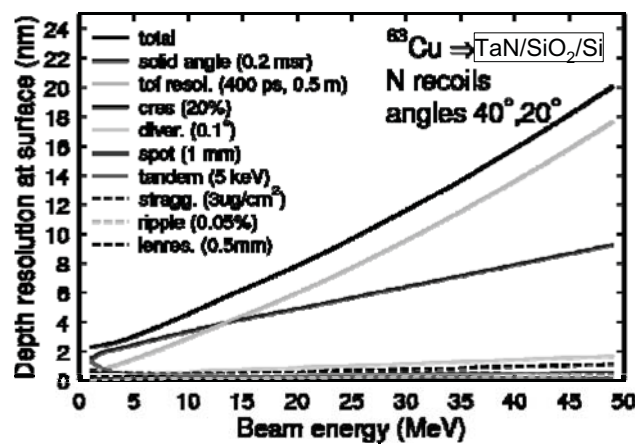
- depth resolution\*:
  - from carbon peak:  $3.7\pm0.1 \text{ g}/\text{cm}^2$
  - $\text{SiO}_2/\text{Si}$  interface:  $4.7\pm1.0 \text{ g}/\text{cm}^2$
- sensitivity: 25x less incident ions for an equivalent number of events

\*assumption: instrumental/method resolution dominates over interface thickness

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## TOF: the smallest the speed, the longest the time

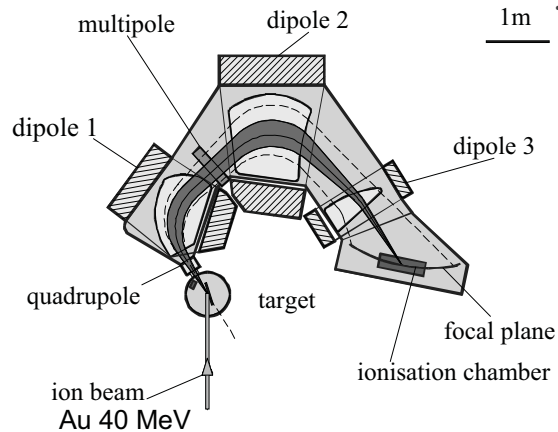


From K. Arstila presentation at CRP-Lisbon, referring to S. Giangrandi presentation at IBA 2007

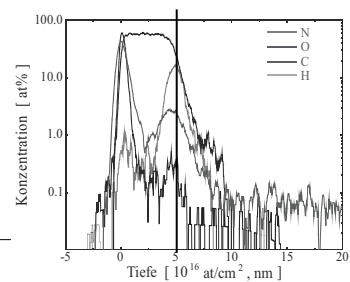
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## HI-ERD: The very big artillery



- UniBwMünchen (Dollinger et al.)
- Q3D magnetic spectro.
- large solid angle: 12 msr
- energy resolution  $\Delta E/E = 5 \times 10^{-4}$  at 5 msr
- depth resolution  $< 1$  nm



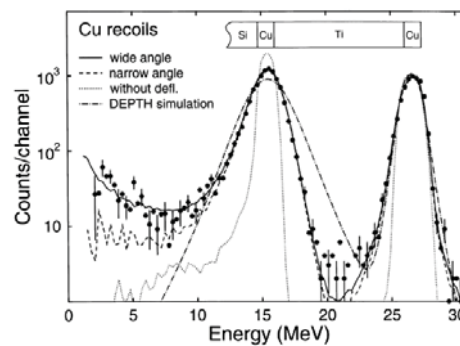
From G. Dollinger presentation at CRP on HI-ERD, Lisbon (2007/11)

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## Effect of multiple scattering on HI-ERD spectrum

53 MeV I  $\rightarrow$  23 nm Cu / 200 nm Ti / 23 nm Cu / Si (20° in, 20° out)

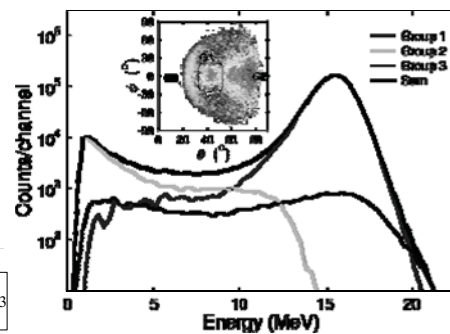
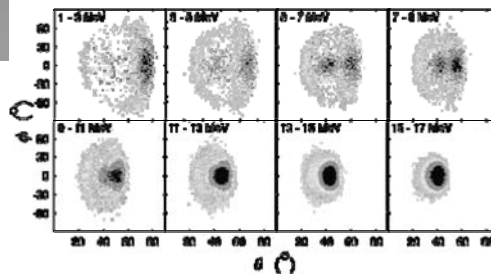
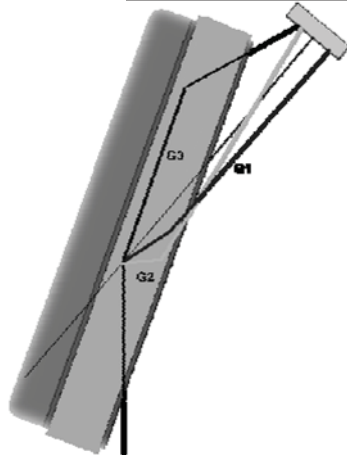


K. Arstila, T. Sajavaara, J. Keinonen, NIMB 174 (2001) 163

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## Effect of multiple scattering on HI-ERD spectrum



From K. Arstila presentation at CRP on HI-ERD, Lisbon (2007/11)  
See also K. Arstila, T. Sajavaara, J. Keinonen, NIMB 174 (2001) 163

## Conclusion

- HI-ERD: attractive concept as one gets a separate spectrum for each target element
- Requires big artillery if depth of probe > 100 nm is required
- ERD-TOF on a Tandatron:
  - excellent depth resolution near surface
  - depth resolution degrades quickly due to MS
  - problem of detection efficiency for light elements: normalise to ERD-absorber
- In general, main contribution to depth resolution quickly becomes MS
  - Grazing incidence, asymmetric contributions
  - MC simulation to analyse